

DCR960G18

Phase Control Thyristor

DS6027-2 June 2019 (LN38846)

FEATURES

Double Side Cooling

APPLICATIONS

• High Surge Capability

High Power Drives

Static Switches

VOLTAGE RATINGS

Part and Ordering

Number

DCR960G18

DCR960G16

DCR960G14

DCR960G12

High Voltage Power Supplies

Repetitive Peak

Voltages

V_{DRM} and V_{RRM}

1800 1600

1400

1200

Conditions

 $T_{vj} = -40^{\circ}C$ to 125°C,

 V_{DRM} , V_{RRM} $t_p = 10ms$,

 $I_{DRM} = I_{RRM} = 60 \text{mA},$

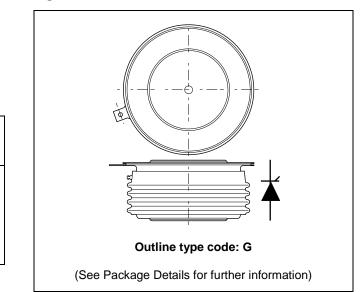
V_{DRM} & V_{RRM} +100V respectively

V_{DSM} & V_{RSM} =

KEY PARAMETERS

	1800 V
$I_{T(AV)}$	960 A
ITSM	14000 A
dV/dt*	1000 V/µs
dl/dt	200 A/µs

* Higher dV/dt selections available



Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR960G18

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order. Fig. 1 Package outline



CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Sid	de Cooled			
I _{T(AV)}	Mean on-state current	Half wave resistive load	960	А
I _{T(RMS)}	RMS value	-	1510	А
Ι _Τ	Continuous (direct) on-state current	-	1360	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{TSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	14.0	kA
l ² t	I ² t for fusing	V _R = 0	0.98	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	5	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.035	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.008	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-	125	°C
T _{stg}	Storage temperature range			-40	140	°C
Fm	Clamping force			12	18	kN

DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditio	ns	Min.	Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125°C		-	60	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, ga	ate open	1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V _{DRM} to 1000A	Repetitive 50Hz	-	200	A/µs
		Gate source 30V, 10Ω ,	Non-repetitive	-	1000	A/µs
		$t_r < 0.5 \mu s, T_j = 125^{\circ}C$				
VT	On-state voltage	I _T = 1500A, T _{case} = 125°C			1.45	V
V _{T(TO)}	Threshold voltage	T _{case} = 125°C		-	0.91	V
۲ _T	On-state slope resistance	T _{case} = 125°C		-	0.36	mΩ
t _{gd}	Delay time	$V_D = 67\% V_{DRM}$, gate source	30V, 10Ω	-	3.0	μs
		$t_r=0.5\mu s, T_j=25^\circ C$				
tq	Turn-off time	$T_j = 125^{\circ}C, V_R = 100V, dl/dt$	= 10A/µs,	-	200	μs
		$dV_{DR}/dt = 20V/\mu s$ linear to 67	7% V _{DRM}			
Qs	Stored charge	$I_T = 1000A$, tp = 1000us,T _j = 125°C, dl/dt =10A/µs,		-	2000	μC
I _{RR}	Reverse recovery current			-	120	А
١L	Latching current	T _j = 25°C,		-	1	А
I _H	Holding current	T _j = 25°C,		-	200	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V _{GT}	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	3	V
V_{GD}	Gate non-trigger voltage	At 40% V _{DRM} , T _{case} = 125°C	0.3	V
I _{GT}	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	300	mA
I _{GD}	Gate non-trigger current	At 40% V _{DRM,} T _{case} = 125°C	20	mA

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CURVES

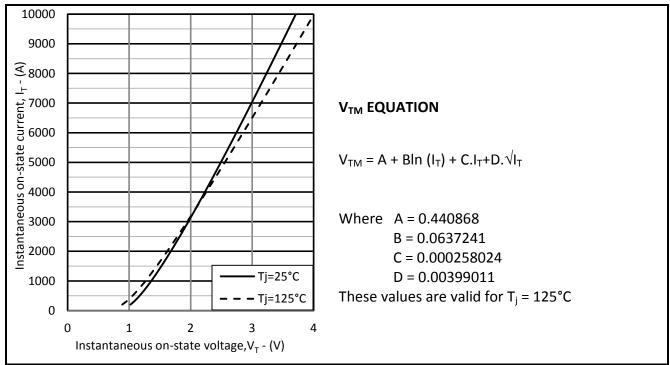


Fig.2 Maximum & minimum on-state characteristics

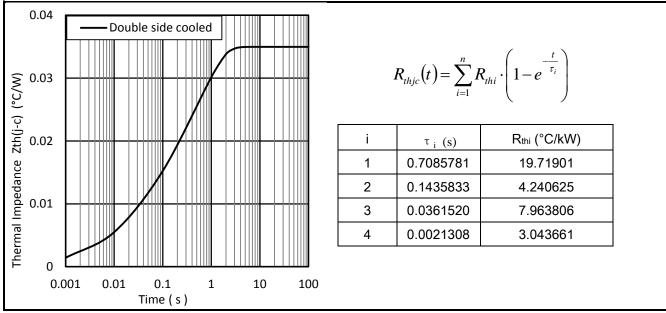
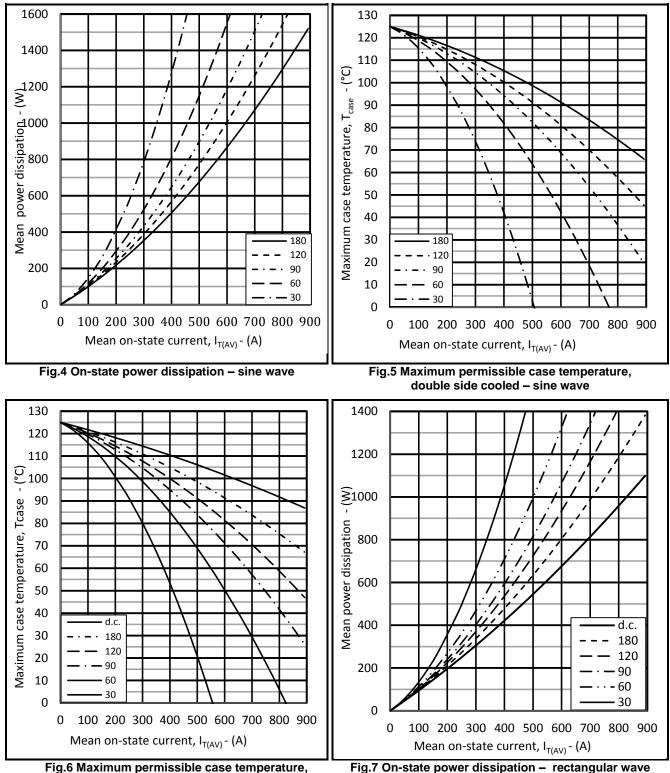


Fig.3 Maximum (limit) transient thermal impedance - junction to case (°C/W)





double side cooled - rectangular wave





DCR960G18

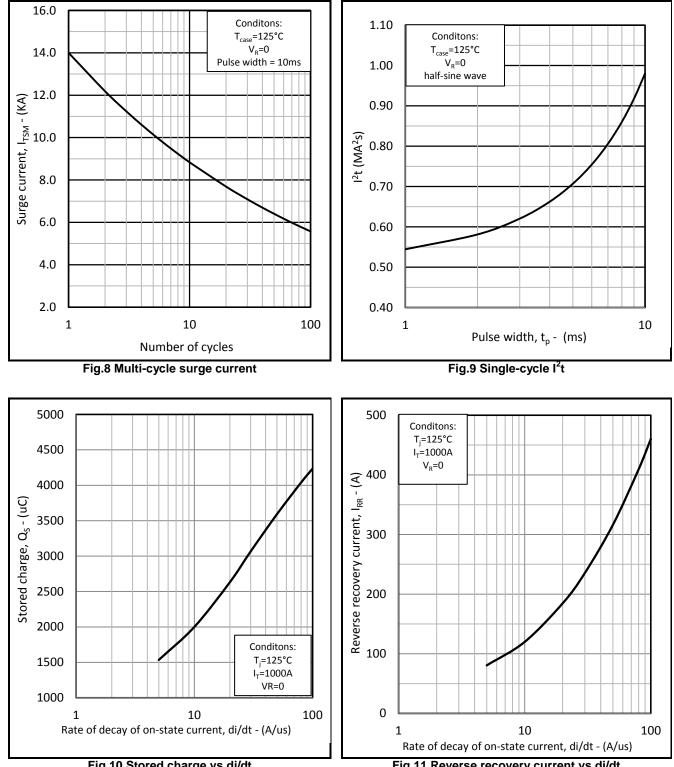


Fig.10 Stored charge vs di/dt

Fig.11 Reverse recovery current vs di/dt

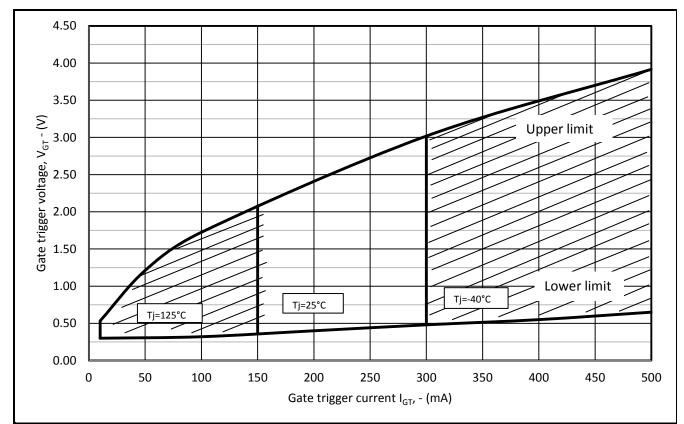


Fig.12 Gate characteristics

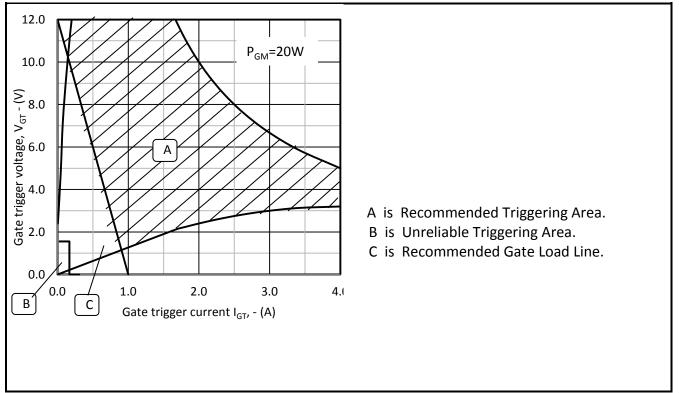


Fig.13 Gate characteristics

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PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

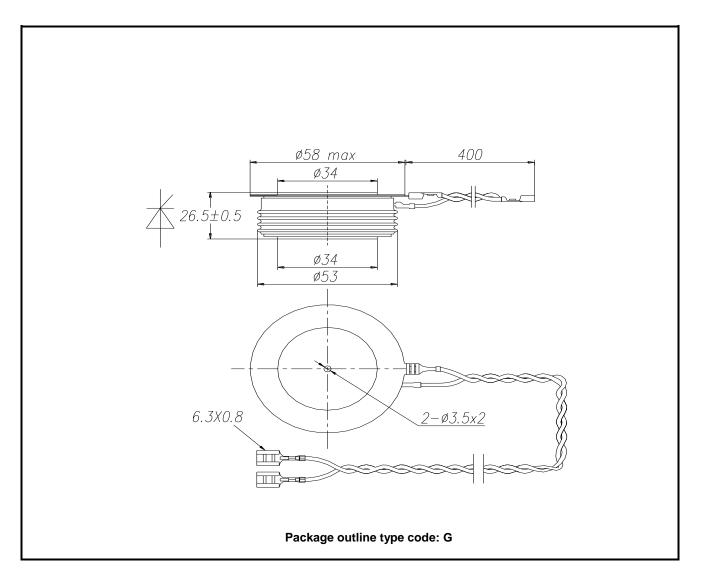


Fig.14 Package outline



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